

4N38X, 4N38AX
4N38, 4N38A



ISOCOM
COMPONENTS



**OPTICALLY COUPLED
ISOLATOR
PHOTOTRANSISTOR OUTPUT**

APPROVALS

- UL recognised, File No. E91231
Package Code " GG "

'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead form :-
 - STD
 - G form
 - SMD approved to CECC 00802
- Certified to EN60950 by :-
Nemko - Certificate No. P01102464

DESCRIPTION

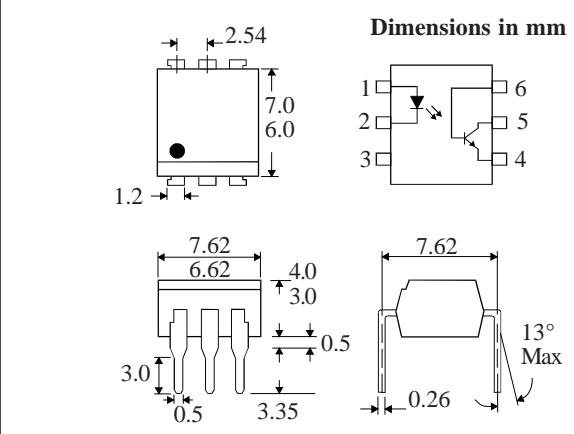
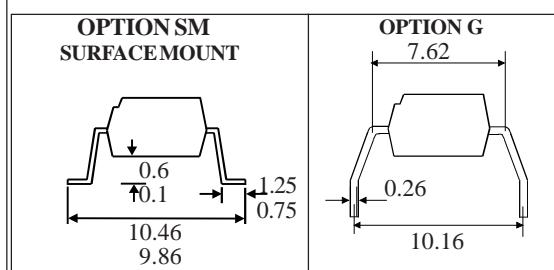
The 4N38, 4N38A series of optically coupled isolators consist of infrared light emitting diode and NPN silicon photo transistor in a standard 6 pin dual in line plastic package.

FEATURES

- Options :-
 - 10mm lead spread - add G after part no.
 - Surface mount - add SM after part no.
 - Tape&reel - add SMT&R after part no.
- High BV_{CEO} (80V min)
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- All electrical parameters 100% tested
- Custom electrical selections available

APPLICATIONS

- DC motor controllers
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances



**ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)**

| | |
|---|------------------|
| Storage Temperature | -55°C to + 150°C |
| Operating Temperature | -55°C to + 100°C |
| Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs) | 260°C |

INPUT DIODE

| | |
|-------------------|-------|
| Forward Current | 60mA |
| Reverse Voltage | 6V |
| Power Dissipation | 105mW |

OUTPUT TRANSISTOR

| | |
|--------------------------------------|-------|
| Collector-emitter Voltage BV_{CEO} | 80V |
| Collector-base Voltage BV_{CBO} | 80V |
| Emitter-collector Voltage BV_{ECO} | 6V |
| Collector Current | 50mA |
| Power Dissipation | 160mW |

POWER DISSIPATION

| | |
|--|-------|
| Total Power Dissipation | 200mW |
| (derate linearly 2.67mW/°C above 25°C) | |

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

| PARAMETER | | MIN | TYP | MAX | UNITS | TEST CONDITION |
|-----------|--|--------------------|-----|-----|-----------------------|---|
| Input | Forward Voltage (V_F) | | 1.2 | 1.5 | V | $I_F = 10\text{mA}$ |
| | Reverse Current (I_R) | | | 10 | μA | $V_R = 6\text{V}$ |
| Output | Collector-emitter Breakdown (BV_{CEO}) (note 2) | 80 | | | V | $I_C = 1\text{mA}$ |
| | Collector-base Breakdown (BV_{CBO}) | 80 | | | V | $I_C = 100\mu\text{A}$ |
| | Emitter-collector Breakdown (BV_{ECO}) | 6 | | | V | $I_E = 100\mu\text{A}$ |
| | Collector-emitter Dark Current (I_{CEO}) | | 50 | | nA | $V_{CE} = 60\text{V}$ |
| | Collector-base Dark Current (I_{CBO}) | | 20 | | nA | $V_{CE} = 60\text{V}$ |
| Coupled | Current Transfer Ratio (CTR) | 20 | | | % | $10\text{mA } I_F, 10\text{V } V_{CE}$ |
| | Collector-emitter Saturation Voltage $V_{CE(SAT)}$ | | 1.0 | | V | $20\text{mA } I_F, 4\text{mA } I_C$ |
| | Input to Output Isolation Voltage V_{ISO} | 5300 7500 | | | V_{RMS} V_{PK} | See note 1 See note 1 |
| | Input-output Isolation Resistance R_{ISO} | 5×10^{10} | | | Ω | $V_{IO} = 500\text{V}$ (note 1) |
| | Response Time (rise) Response Time (fall) | | 2 | 2 | μs | $V_{cc} = 5\text{V},$ $I_F = 10\text{mA}, R_L = 75\Omega$ (FIG 1) |

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

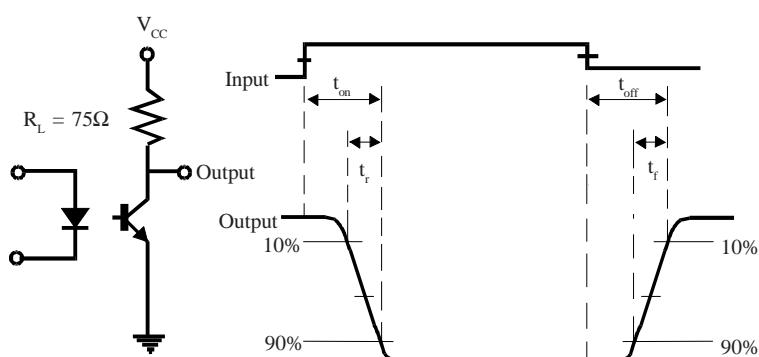


FIG 1

